VSK.91..PbF Series

Vishay Semiconductors

Standard Diodes, 100 A (ADD-A-PAK Generation 5 Power Modules)



ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA			
	04	400	500				
	06	600	700				
	08	800	900				
VSK.91	10	1000	1100	10			
	12	1200	1300				
	14	1400	1500				
	16	1600	1700				

FORWARD CONDUCTION						
PARAMETER	SYMBOL		TEST CONE	VALUES	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave			100 100	A °C
Maximum RMS forward current	I _{F(RMS)}	DC at 90 °C	case temperatui	re	157	
	, ,	t = 10 ms	No voltage		2020	А
Maximum peak, one-cycle		t = 8.3 ms	reapplied	 	2110	
forward, non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		1700	
34. go 34. 13. 11		t = 8.3 ms	reapplied	Sinusoidal half wave,	1780	
	l ² t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	20.43	kA ² s
Maximum I ² t for fusing		t = 8.3 ms	reapplied		18.65	
Maximum i-t for fusing		t = 10 ms	100 % V _{RRM}		14.45	
		t = 8.3 ms	reapplied		13.19	
Maximum $I^2\sqrt{t}$ for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied			204.3	kA²√s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum			0.79	V
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			0.87	V
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			1.78	mΩ
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			1.57	11152
Maximum forward voltage drop	V_{FM}	$I_{FM} = \pi \times I_{F(AV)}$, $T_J = 25 ^{\circ}C$, $t_p = 400 \mu s$ square wave			1.45	V

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak reverse leakage current	I _{RRM}	T _J = 150 °C	10	mA			
RMS insulation voltage	V _{INS}	50 Hz, circuit to base, all terminals shorted	3500 (1 s)	V			



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THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction operating and storage temperature range		T _J , T _{Stg}		- 40 to 150	°C		
Maximum thermal resistance, junction to case per junction		R _{thJC}	DC operation	0.35	35 K/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface flat, smooth and greased		1000		
Mounting torque : 10.0/	to heatsink		A mounting compound is recommended and	5	Nimo		
Mounting torque ± 10 % -	busbar		the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	4	Nm		
Approximate weight				110	g		
				4	OZ.		
Case style			JEDEC	ADD-A-PAK	(TO-240AA)		

△R CONDUCTION PER JUNCTION											
DEVICES	SINE HALF WAVE CONDUCTION				RECTANGULAR WAVE CONDUCTION				UNITS		
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.91	0.052	0.064	0.082	0.112	0.164	0.043	0.069	0.088	0.115	0.165	°C/W

Note

 $\bullet \quad \text{Table shows the increment of thermal resistance } R_{\text{th}JC} \text{ when devices operate at different conduction angles than } DC$

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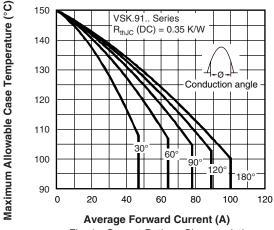


Fig. 1 - Current Ratings Characteristics

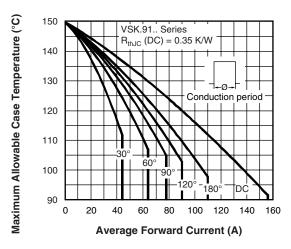


Fig. 2 - Current Ratings Characteristics

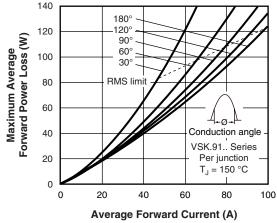


Fig. 3 - Forward Power Loss Characteristics

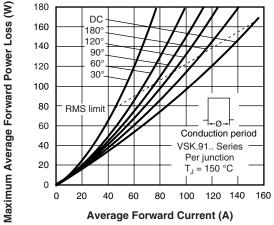
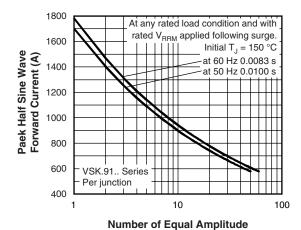


Fig. 4 - Foward Power Loss Characteristics



Half Cycle Current Pulses (N)
Fig. 5 - Maximum Non-Repetitive Surge Current

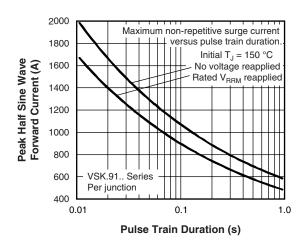
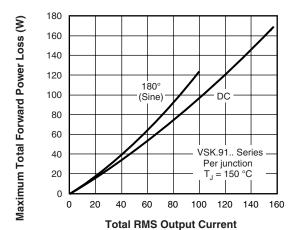


Fig. 6 - Maximum Non-Repetitive Surge Current



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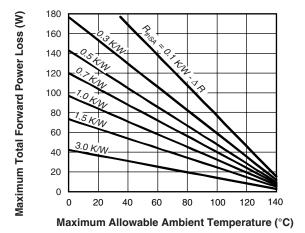
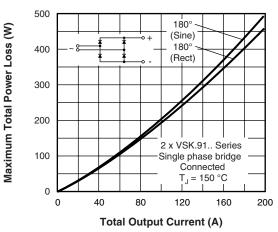


Fig. 7 - Forward Power Loss Characteristics



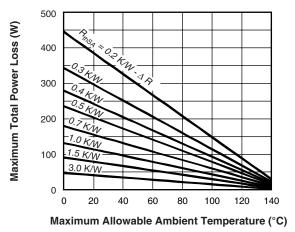
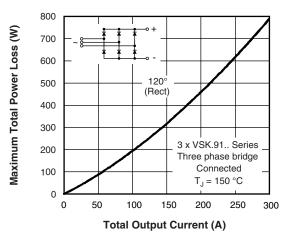


Fig. 8 - Forward Power Loss Characteristics



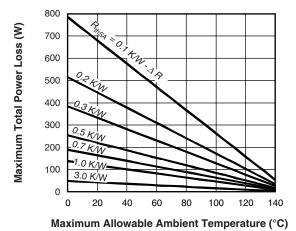


Fig. 9 - Forward Power Loss Characteristics

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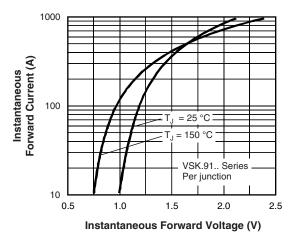


Fig. 10 - Forward Voltage Drop Characteristics

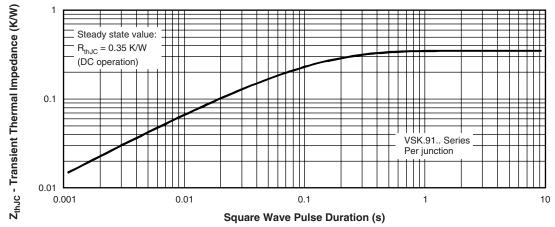


Fig. 11 - Thermal Impedance Z_{thJC} Characteristic

ORDERING INFORMATION TABLE

|1| - Module type

2 - Circuit configuration (see Circuit Configuration table)

3 - Current code

4 - Voltage code (see Voltage Ratings table)

5 - P = Lead (Pb)-free

Note

• To order the optional hardware go to www.vishay.com/doc?95172



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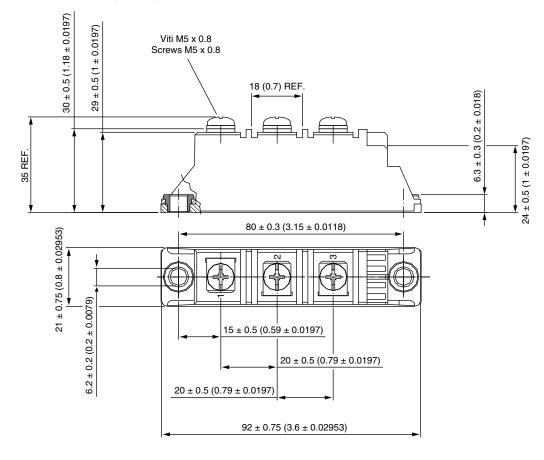
CIRCUIT CONFIGURATION						
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
	D	VSKD				
		(1) $\tilde{\circ}$ $\dot{\circ}$ (2) $\tilde{\circ}$ (3)				
Two diodes doubler circuit						
		VSKC				
	С	(1) 0 (2) (3)				
Two diodes common cathodes						
		VSKJ				
		(1) O + O (2) O (3)				
Two diodes common anodes	J					
		VSKE				
	E	(2) 0 (3)				
Single diode						

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95015				



ADD-A-PAK Diode

DIMENSIONS in millimeters (inches)



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